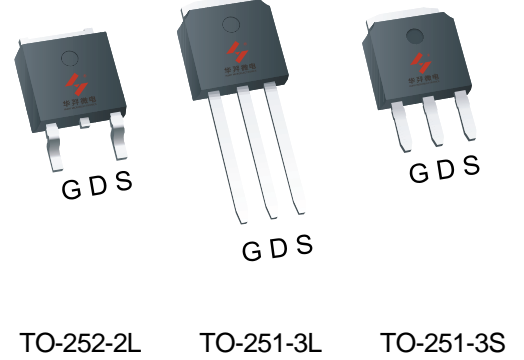


## N-Channel Enhancement Mode MOSFET

### Feature

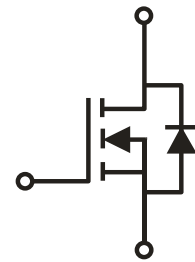
- 20V/90A  
 $R_{DS(ON)} = 3.2$  @  $V_{GS} = 4.5V$   
 $R_{DS(ON)}$  @  $V_{GS} = 2.5V$   
 $R_{DS(ON)} = 11.3$  @  $V_{GS} = 1.9V$
- 100% Avalanche Tested
- 100% DVDS
- Reliable and Rugged
- Halogen Free and Green Devices Available  
 (RoHS Compliant)

### Pin Description




### Applications

- Li-battery protection
- Motor control



Single N-Channel MOSFET

### Ordering and Marking Information

 <b>D</b> <b>HYG055N02</b> <b>XYMXXXXXX</b>	<b>Package Code</b> D: TO-252-2L    U: TO-251-3L    V: TO-251-3S  <b>Date Code</b> XYMXXXXXX
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Note: HUAYI halogen free products contain molding compounds/die attach materials and 100% matte tin plate Termination finish; which are fully compliant with RoHS. HUAYI halogen free products meet or exceed the halogen free requirements of IPC/JEDEC J-STD-020 for MSL classification at halogen free peak reflow temperature. HUAYI defines Green to mean halogen free (RoHS compliant) and halogen free (Br or Cl does not exceed 900ppm by weight in homogeneous material and total of Br and Cl does not exceed 1500ppm by weight).

HUAYI reserves the right to make changes, corrections, enhancements, modifications, and improvements to this product and/or to this document at any time without notice.

## Absolute Maximum Ratings

Symbol	Parameter	Rating	Unit	
<b>Common Ratings</b> (Tc=25°C Unless Otherwise Noted)				
V <sub>DSS</sub>	Drain-Source Voltage	20	V	
V <sub>GSS</sub>	Gate-Source Voltage	12	V	
T <sub>J</sub>	Junction Temperature Range	-55 to 175	°C	
T <sub>STG</sub>	Storage Temperature Range		°C	
I <sub>S</sub>	Source Current-Continuous(Body Diode)	Tc=25°C	90	A
<b>Mounted on Large Heat Sink</b>				
I <sub>DM</sub>	Pulsed Drain Current *	Tc=25°C	270	A
I <sub>D</sub>	Continuous Drain Current	Tc=25°C	90	A
		Tc=100°C	65	A
P <sub>D</sub>	Maximum Power Dissipation	Tc=25°C	60	W
		Tc=100°C	30	W
R <sub>JC</sub>	Thermal Resistance, Junction-to-Case		2.5	°C/W
R <sub>JA</sub>	Thermal Resistance, Junction-to-Ambient **		75	°C/W
E <sub>AS</sub>	Single Pulsed-Avalanche Energy ***	L=0.3mH	110	mJ

Note: \* Repetitive rating pulse width limited by max.junction temperature.

\*\* Surface mounted on 1in2 FR-4 board.

\*\*\* Limited by T<sub>Jmax</sub>, starting T<sub>J</sub>=25°C, L = 0.3mH, R<sub>e</sub>= 25 , V<sub>GS</sub>=4.5V.

## Electrical Characteristics (Cont.) (Tc =25°C Unless Otherwise Noted) Bt@CI Bt@CUSUj8U2'D9 DSry1USU#

Symbol	Parameter	Test Conditions	HYG055N02KR1			Unit
			Min	Typ.	Max	
<b>Dynamic Characteristics</b>						
R <sub>G</sub>	Gate Resistance	V <sub>GS</sub> =0V, V <sub>DS</sub> =0V, F=1MHz	-	1.6	-	
C <sub>iss</sub>	Input Capacitance	V <sub>GS</sub> =0V, V <sub>DS</sub> = 20V, Frequency=1MHz	-	1476	-	pF
C <sub>oss</sub>	Output Capacitance		-	259	-	
C <sub>rss</sub>	Reverse Transfer Capacitance		-	206	-	
t <sub>d(ON)</sub>	Turn-on Delay Time					

## Typical Operating Characteristics

Figure 1: Power Dissipation

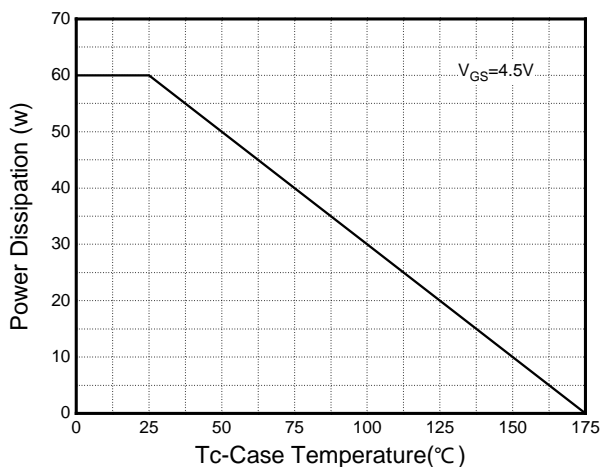


Figure 2: Drain Current

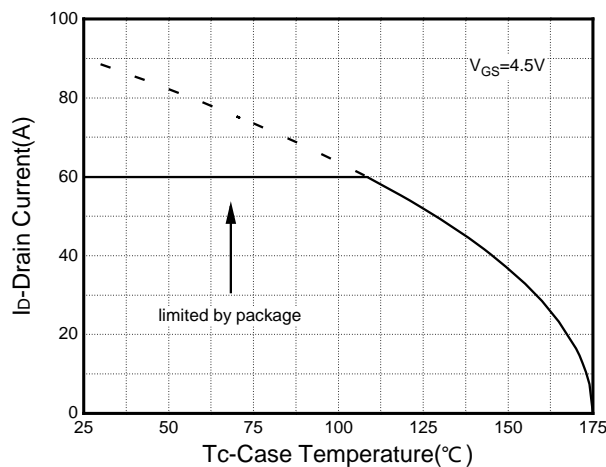


Figure 3: Safe Operation Area

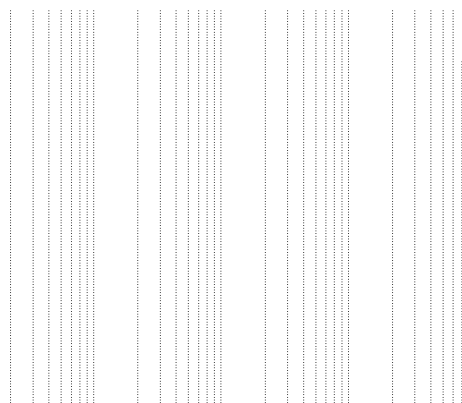


Figure 4: Thermal Transient Impedance

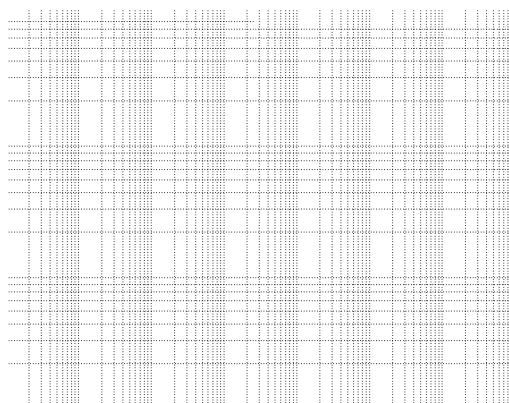


Figure 5: Output Characteristics

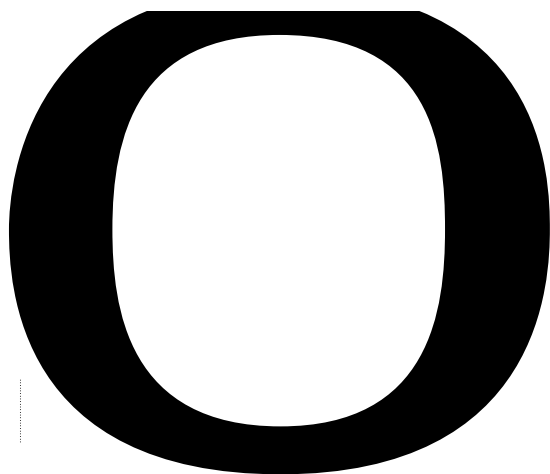


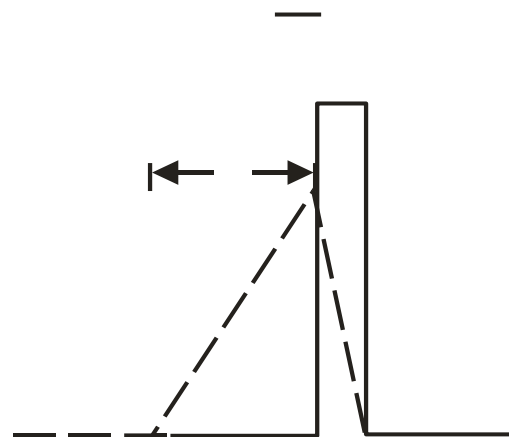
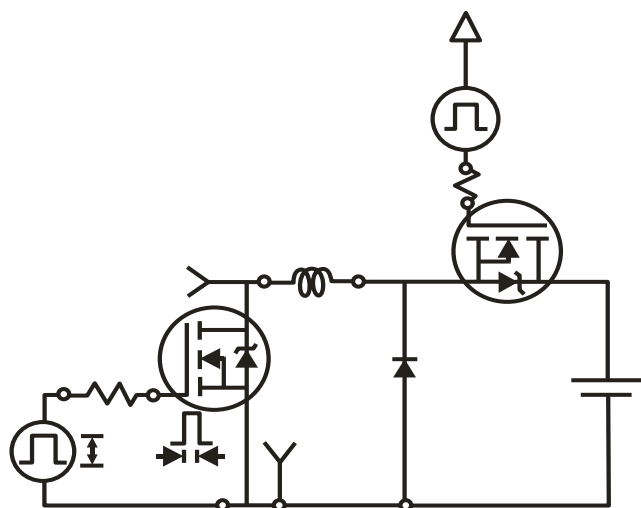
Figure 6: Drain-Source On Resistance



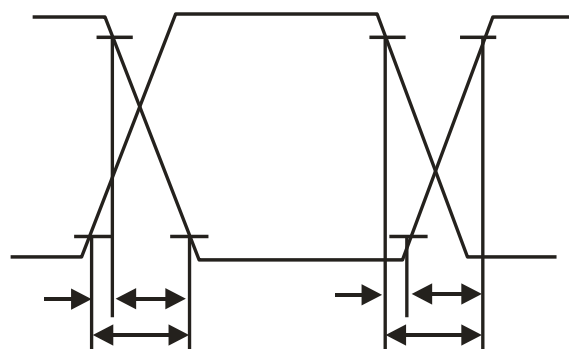
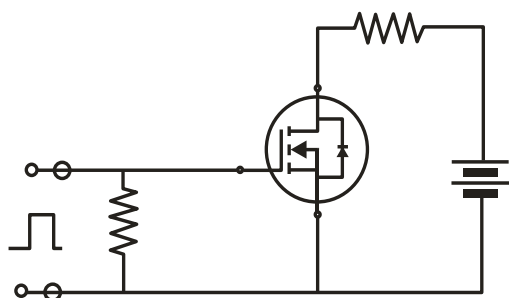
## Typical Operating Characteristics(Cont.)

Figure 7: On-Resir905 (43 9 Tf -303.7 .98 ( )-

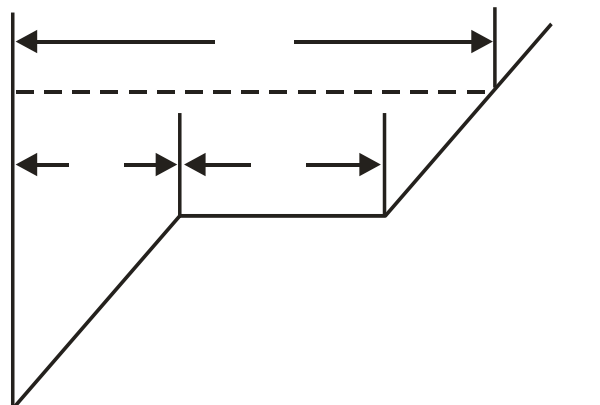
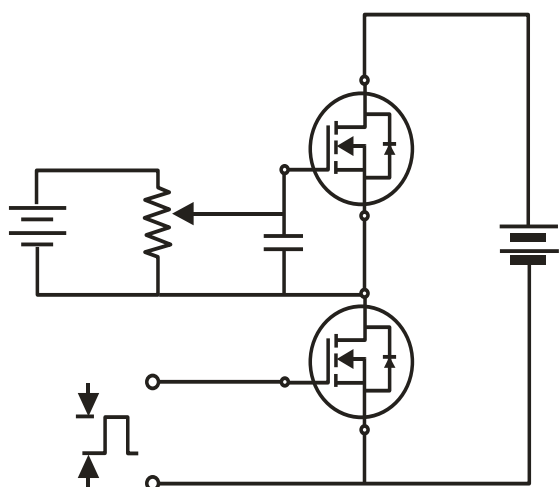
**Avalanche Test Circuit**



**Switching Time Test Circuit**



**Gate Charge Test Circuit**

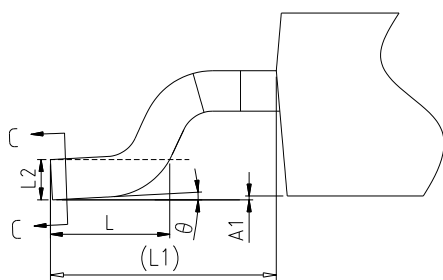
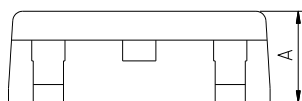
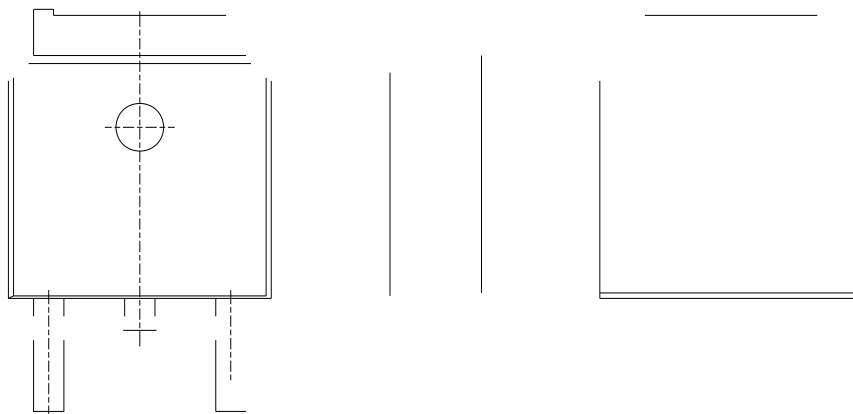


## Device Per Unit

Package Type	Unit	Quantity
TO-252-2L	Tube	75
TO-252-2L	Reel	2500
TO-251-3L	Tube	75
TO-251-3S	Tube	75

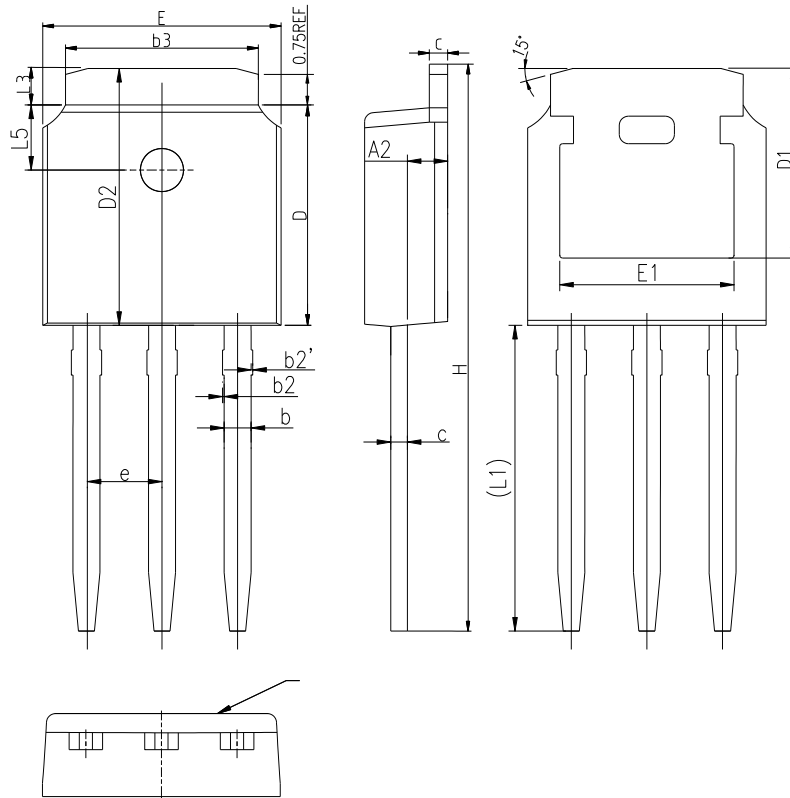
## Package Information

### TO-252-2L



COMMON DIMENSIONS			
SYMBOL	mm		
	MIN	NOM	MAX
A	2.20	2.30	2.40
A1	0.00	-	0.12
A2	0.97	1.07	1.17
b	0.68	0.78	0.90
b3	5.20	5.33	5.46
c	0.43	0.53	0.61
D	5.98	6.10	6.22
D1	5.30REF		
E	6.40	6.60	6.73
E1	4.63	-	-
e	2.286BSC		
H	9.40	10.10	10.50
L	1.38	1.50	1.75
L1	2.90REF		
L2	0.51BSC		
L3	0.88	-	1.28
L4	0.50	-	1.00
L5	1.65	1.80	1.95
	0°	-	8°

TO-251-3L



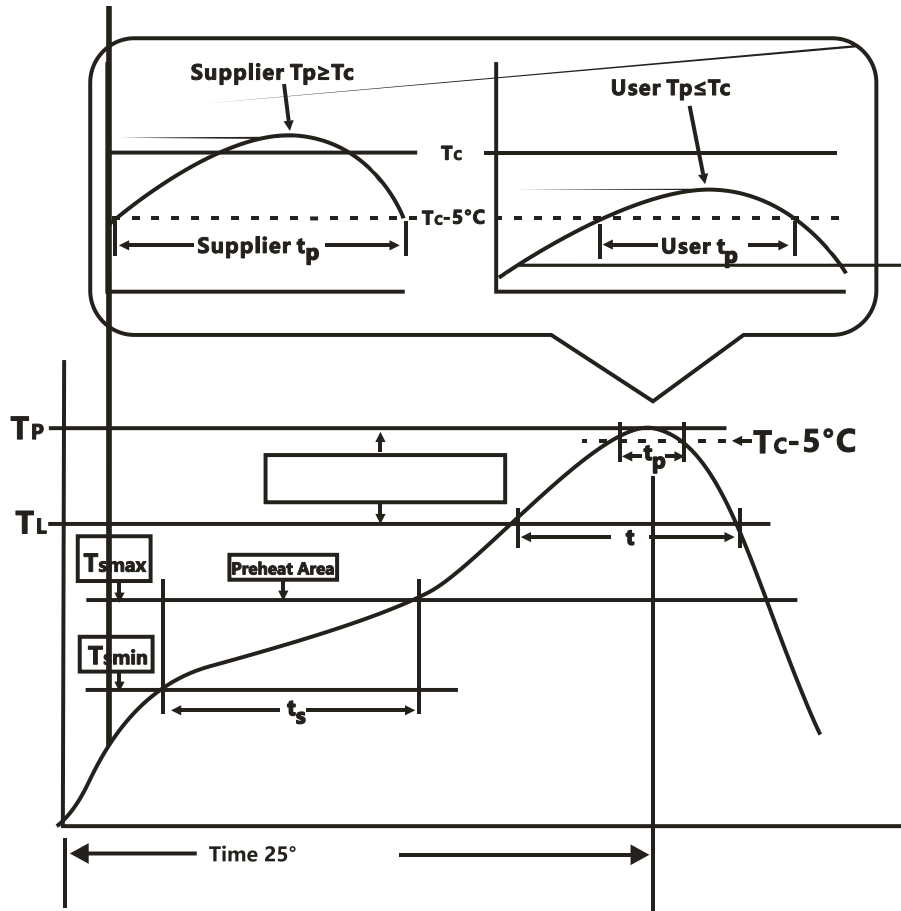
COMMON DIMENSIONS			
SYMBOL	mm		
	MIN	NOM	MAX
A	2.20	2.30	2.38
A2	0.97	1.07	1.17
b	0.68	0.78	0.90
b2	0.00	0.04	0.10
b2'	0.00	0.04	0.10
b3	5.20	5.33	5.46
c	0.43	0.53	0.61
D	5.98	6.10	6.22
D1	4.30	5.30	6.00
D2	6.92	7.12	7.32
E	6.40	6.60	6.73
E1	4.63	-	-
e	2.286BSC		
H	16.22	16.52	16.82
L1	9.15	9.40	9.65
L3	0.88	1.02	1.28
L5	1.65	1.80	1.95



TO-251-3S

COMMON DIMENSIONS			
SYMBOL	mm		
	MIN	NOM	MAX

Classification Profile



Classification Reflow Profiles

Profile Feature	Sn-Pb Eutectic Assembly	Pb-Free Assembly
<b>Preheat &amp; Soak</b>		
Temperature min ( $T_{smin}$ )	100 °C	150 °C
Temperature max ( $T_{smax}$ )	150 °C	200 °C
Time ( $T_{smin}$ to $T_{smax}$ ) ( $t_s$ )	60-120 seconds	60-120 seconds
Average ramp-up rate ( $T_{smax}$ to $T_P$ )	3 °C/second max.	3°C/second max.
Liquidous temperature ( $T_L$ )	183 °C	217 °C
Time at liquidous ( $t_l$ )	60-150 seconds	60-150 seconds
Peak package body Temperature ( $T_p$ )*	See Classification Temp in table 1	See Classification Temp in table 2
Time ( $t_p$ )** within 5°C of the specified classification temperature ( $T_c$ )	20** seconds	30** seconds
Average ramp-down rate ( $T_p$ to $T_{smax}$ )	6 °C/second max.	6 °C/second max.
Time 25°C to peak temperature	6 minutes max.	8 minutes max.
*Tolerance for peak profile Temperature ( $T_p$ ) is defined as a supplier minimum and a user maximum.		
** Tolerance for time at peak profile temperature ( $t_p$ ) is defined as a supplier minimum and a user maximum.		

Table 1. SnPb Eutectic Process Classification Temperatures (Tc)

Package Thickness	Volume mm <350	Volume mm 350
2.5 mm	235 °C	220 °C
	220 °C	220 °C

Table 2. Pb-free Process Classification Temperatures (Tc)

Package Thickness	Volume mm <350	Volume mm 350-2000	Volume mm 2000
<1.6 mm	260 °C	260 °C	260 °C
1.6 mm 2.5 mm	260 °C	250 °C	245 °C
2.5 mm	250 °C	245 °C	245 °C

## Reliability Test Program

Test item	Method	Description
SOLDERABILITY	JESD-22, B102	5 Sec, 245°C
HTRB	JESD-22, A108	168/500